N-Channel Silicon MOSFET



CPH3407

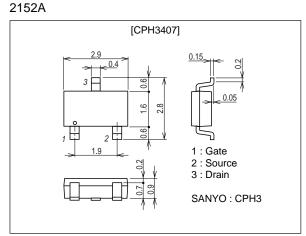
Ultrahigh-Speed Switching Applications

Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 2.5V drive.

Package Dimensions

unit : mm



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	ID		5	A
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	20	A
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)	1.2	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	20			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS} (off)	V _{DS} =10V, I _D =1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =3A	7	10		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=3A, VGS=4V		28	37	mΩ
	R _{DS} (on)2	I _D =1A, V _{GS} =2.5V		35	50	mΩ

Marking : KG

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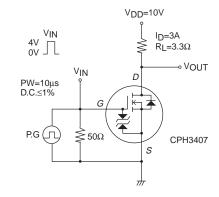
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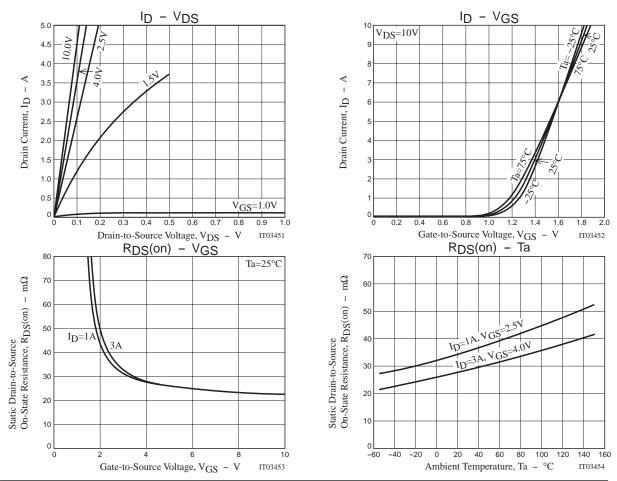
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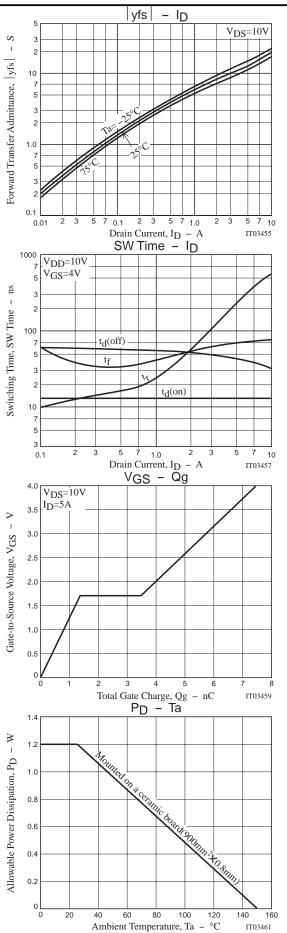
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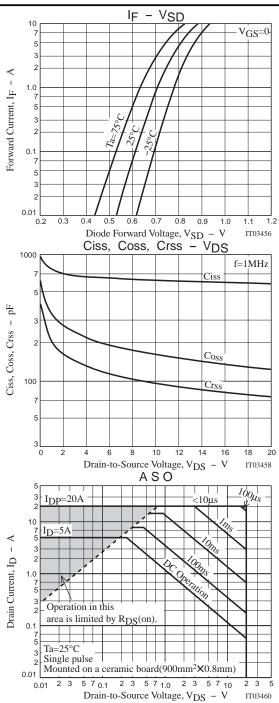
Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		630		pF
Output Capacitance	Coss	VDS=10V, f=1MHz		160		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		95		pF
Turn-ON Delay Time	td(on)	See specified Test Circuit		13		ns
Rise Time	tr	See specified Test Circuit		110		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit		47		ns
Fall Time	tf	See specified Test Circuit		65		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =4V, I _D =5A		7.3		nC
Gate-to-Source Charge	Qgs	VDS=10V, VGS=4V, ID=5A		1.4		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =4V, I _D =5A		2.1		nC
Diode Forward Voltage	VSD	IS=5A, VGS=0		0.8	1.2	V

Switching Time Test Circuit









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